

LM392

Low Power Operational Amplifier and Comparator

The LM392 contains two functions: an op amp and a comparator. Both devices can operate on single-supply power and both have a common-mode range down to ground. Operation from split power supplies is also possible. Low power-supply current is independent of the supply voltage level. The output of the comparator interfaces directly with either TTL or CMOS logic. Low quiescent current makes the LM392 ideal for portable equipment.

Features

- Wide Power-Supply Range: 3 V to 32 V
- Low Input Offset Voltage: 2 mV
- Low Quiescent Current: 600 μ A
- Input CMV Range includes GND
- Op Amp is Unity Gain Stable
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Level Detectors
- Voltage Controlled Oscillators
- Transducer Amplifiers



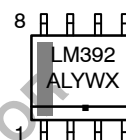
ON Semiconductor®

<http://onsemi.com>

MARKING DIAGRAM



SOIC-8 NB
CASE 751



XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
• = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

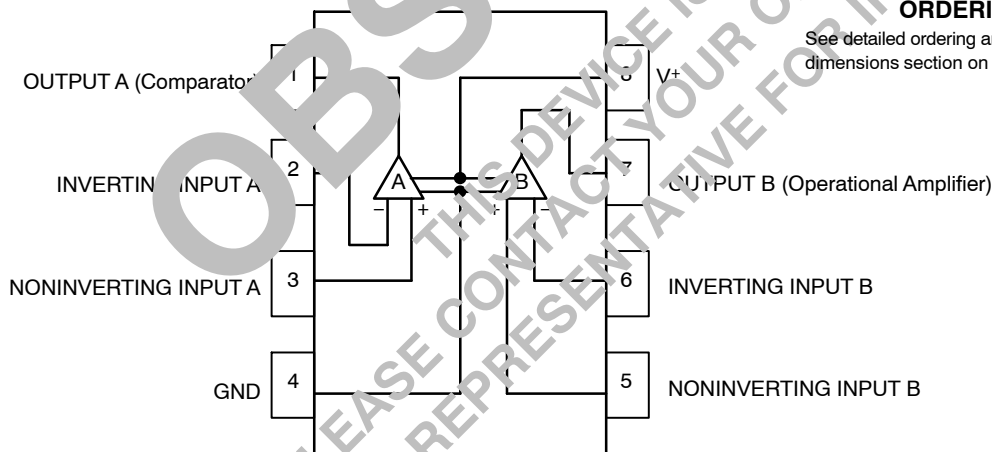


Figure 1. Logic Diagram and Pinout

LM392

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V_S	32 or ± 16	V
Differential Input Voltage	V_{IDR}	32	V
Input Voltage	V_I	0.3 to 32	V
Output Short – Circuit to Ground	t_{SO}	Continuous	
Thermal Impedance	θ_{JA}	160	$^{\circ}\text{C}/\text{W}$
Storage Temperature Range	T_{stg}	-65 to 150	$^{\circ}\text{C}$
Lead Temperature (Soldering, 10 Seconds)		260	$^{\circ}\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

OBSOLETE
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LM392

ELECTRICAL CHARACTERISTICS (Both Amplifiers) ($V^+ = 5\text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Conditions	T_A	LM392			Unit
			Min	Typ	Max	
Input Offset Voltage	At output switch point, $V_O = 1.4\text{ V}$, $R_S = 0\ \Omega$, $V^+ = 5\text{ V}$ to 30 V , $V_{CM} = 0$ to ($V^+ - 1.5\text{ V}$)	25°C		± 2	± 5	mV
		0°C to 70°C			± 7	
Input Bias Current	$IN(+)$ or $IN(-)$, $V_{CM} = 0\text{ V}$	25°C		50	205	nA
	$IN(+)$ or $IN(-)$	0°C to 70°C			400	
Input Offset Current	$IN(+)$ or $IN(-)$	25°C		± 5	± 50	nA
		0°C to 70°C			± 150	
Input Common-Mode Voltage Range	$V^+ = 30\text{ V}$ (Note 1)	25°C	0		$V^+ - 1.5$	V
		0°C to 70°C	0		$V^+ - 2$	
Supply Current	No Load	$V^+ = 30\text{ V}$		1	2	mA
		$V^+ = 5\text{ V}$		0.5	1	
Amplifier-to-Amplifier Coupling	$f = 1\text{ kHz}$ to 20 kHz , Input Referred	25°C		-78		dB
Differential Input Voltage	All $V_{IN} \geq V$ (or V^- , if $U_{IN} = 0$)	0°C to 70°C			32	V

ELECTRICAL CHARACTERISTICS ($V^+ = 5\text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Conditions	T _A	LM392			Unit
			Min.	Typ.	Max	
OP AMP ONLY						
Large Signal Voltage Gain	V ⁺ = 5 V, V _O Swing = 1 V to 11 V, R _L = 1 kΩ	25°C	20	100		V/mV
Output Voltage Swing, High (V _{OH})	R _L = 1 kΩ	25°C	V ⁺ - 1.7			V
Output Voltage Swing, Low (V _{OL})	R _L = 2 kΩ	25°C			20	mV
Common-Mode Rejection Ratio	V _{CM} = 0 to V ⁺ - 1.5 V	25°C	65	70		dB
Power Supply Rejection Ratio		25°C	65	100		dB
Output Current Source	V _{IN(+)} = 1 V, V _{IN(-)} = 0 V, V ⁺ = 15 V, V _O = 2 V	25°C	20	40		mA
Output Current Sink	V _{IN(-)} = 1 V, V _{IN(+)} = 0 V, V ⁺ = 15 V, V _O = 2 V	25°C	10	20		mA
	V _{IN(-)} = 1 V, V _{IN(+)} = 0 V, V ⁺ = 15 V, V _O = 200 mV	25°C	12	50		μA
Input Offset Voltage Drift	R _S = 0 Ω (0°C to 70°C)	0°C to 70°C		7		μV/°C
Input Offset Current Drift	R _S = 0 Ω (0°C to 70°C)	0°C to 70°C		10		pA/°C
COMPARATOR ONLY						
Voltage Gain	R _L ≥ 15 kΩ, V ⁺ = 15 V	25°C	50	200		V/mV
Large Signal Response Time	V _{IN} = TTL Logic Swing, V _{REF} = 1.4 V, V _{RL} = 5 V, R _L = 5.1 kΩ	25°C		200		ns
Response Time	V _{RL} = 5 V, R _L = 5.1 kΩ	25°C		600		ns
Output Sink Current	V _{IN(-)} = 1 V, V _{IN(+)} = 0 V, V _O ≥ 1.5 V	25°C	6	16		mA
Saturation Voltage	V _{IN(-)} ≥ 1 V, V _{IN(+)} = 0, I _{SINK} ≤ 4 mA	25°C		250	400	mV
	V _{IN(-)} ≥ 1 V, V _{IN(+)} = 0, I _{SINK} ≤ 4 mA	0°C to 70°C			700	mV
Output Leakage Current	V _{IN(-)} = 0, V _{IN(+)} ≥ 1 V, V _O = 5 V	25°C		0.1		nA
	V _{IN(-)} = 0, V _{IN(+)} ≥ 1 V, V _O = 30 V	25°C			1.0	μA

1. The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V . The upper end of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go to 32 V without damage.

LM392

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
LM392DR2G	0°C to +70°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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SCALE 1:1

SOIC-8 NB
CASE 751-07
ISSUE AK

DATE 16 FEB 2011



NOTES:

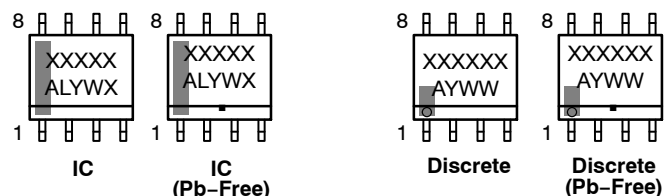
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

GENERIC
MARKING DIAGRAM*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

XXXXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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CASE 751-07
ISSUE AK

DATE 16 FEB 2011

STYLE 1: PIN 1. EMITTER 2. COLLECTOR 3. COLLECTOR 4. EMITTER 5. EMITTER 6. BASE 7. BASE 8. EMITTER	STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. BASE, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1	STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1	STYLE 4: PIN 1. ANODE 2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE
STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE	STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE	STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd	STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1
STYLE 9: PIN 1. EMITTER, COMMON 2. COLLECTOR, DIE #1 3. COLLECTOR, DIE #2 4. EMITTER, COMMON 5. EMITTER, COMMON 6. BASE, DIE #2 7. BASE, DIE #1 8. EMITTER, COMMON	STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. BIAS 2 7. INPUT 8. GROUND	STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN	STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
STYLE 17: PIN 1. VCC 2. V2OUT 3. V1OUT 4. TXE 5. RXE 6. VEE 7. GND 8. ACC	STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6	STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE
STYLE 25: PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT	STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
STYLE 29: PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1	STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		

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